## 1 Product profile

### 1.1 General description

Planar PIN diode in a SOD523 ultra small plastic SMD package.

#### 1.2 Features and benefits

- · High voltage, current controlled
- RF resistor for RF attenuators and switches
- · Low diode capacitance
- · Low diode forward resistance
- · Very low series inductance
- For applications up to 6 GHz
- AEC-Q101 qualified

### 1.3 Applications

· RF attenuators and switches

## 2 Pinning information

Table 1. Discrete pinning

| Pin | Description |     | Simplified outline | Symbol |
|-----|-------------|-----|--------------------|--------|
| 1   | cathode     | [1] |                    | 14     |
| 2   | anode       |     | 1 2                | sym006 |

<sup>[1]</sup> The marking bar indicates the cathode.

## 3 Ordering information

**Table 2. Ordering information** 

| Type number | Package | Package                                  |         |  |  |  |  |
|-------------|---------|--|---------|--|--|--|--|
|             | Name    | Description                              | Version |  |  |  |  |
| BAP64-02    | -       | plastic surface-mounted package; 2 leads | SOD523  |  |  |  |  |



Silicon PIN diode

## 4 Marking

Table 3. Marking

| Type number | Marking code |
|-------------|--------------|
| BAP64-02    | S            |

# 5 Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter               | Conditions              | Min | Max  | Unit |
|------------------|-------------------------|-------------------------|-----|------|------|
| $V_R$            | reverse voltage         |                         | -   | 175  | V    |
| I <sub>F</sub>   | forward current         |                         | -   | 100  | mA   |
| P <sub>tot</sub> | total power dissipation | T <sub>sp</sub> = 90 °C | -   | 715  | mW   |
| T <sub>stg</sub> | storage temperature     |                         | -65 | +150 | °C   |
| Tj               | junction temperature    |                         | -65 | +150 | °C   |

### 6 Thermal characteristics

**Table 5. Thermal characteristics** 

| Symbol                | Parameter  | Conditions | Тур | Unit |
|-----------------------|--|------------|-----|------|
| R <sub>th(j-sp)</sub> | thermal resistance from junction to solder point |            | 85  | K/W  |

### 7 Characteristics

#### **Table 6. Characteristics**

 $T_j$  = 25 °C unless otherwise specified.

| Symbol         | Parameter                | Conditions                 |     | Min | Тур  | Max  | Unit |
|----------------|--------------------------|----------------------------|-----|-----|------|------|------|
| V <sub>F</sub> | forward voltage          | I <sub>F</sub> = 50 mA     |     | -   | 0.95 | 1.1  | V    |
| I <sub>R</sub> | reverse current          | V <sub>R</sub> = 60 V      |     | -   | -    | 10   | μΑ   |
|                |                          | V <sub>R</sub> = 20 V      |     | -   | -    | 1    | μΑ   |
| C <sub>d</sub> | diode capacitance        | see Figure 1; f = 1 MHz;   |     |     |      |      |      |
|                |                          | V <sub>R</sub> = 0 V       |     | -   | 0.48 | -    | pF   |
|                |                          | V <sub>R</sub> = 1 V       |     | -   | 0.35 | -    | pF   |
|                |                          | V <sub>R</sub> = 20 V      |     | -   | 0.23 | 0.35 | pF   |
| $r_D$          | diode forward resistance | see Figure 2; f = 100 MHz; | [1] |     |      |      |      |
|                |                          | I <sub>F</sub> = 0.5 mA    |     | -   | 20   | 40   | Ω    |
|                |                          | I <sub>F</sub> = 1 mA      |     | -   | 10   | 20   | Ω    |
|                |                          | I <sub>F</sub> = 10 mA     |     | -   | 2.0  | 3.8  | Ω    |
|                |                          | I <sub>F</sub> = 100 mA    |     | -   | 0.7  | 1.35 | Ω    |

### Silicon PIN diode

| Symbol         | Parameter                | Conditions  | Min | Тур  | Max | Unit |
|----------------|--------------------------|---|-----|------|-----|------|
| TL             | charge carrier life time | when switched from I <sub>F</sub> = 10 mA to I <sub>R</sub> = 6 mA; R <sub>L</sub> = 100 $\Omega$ ; measured at I <sub>R</sub> = 3 mA | -   | 1.55 | -   | μs   |
| L <sub>S</sub> | series inductance        |   | -   | 0.6  | _   | nH   |

[1] Guaranteed on AQL basis: inspection level S4, AQL 1.0.

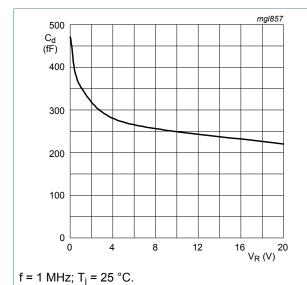
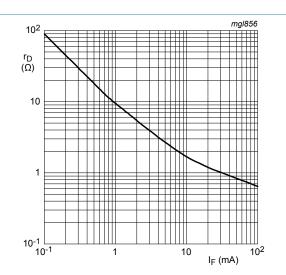


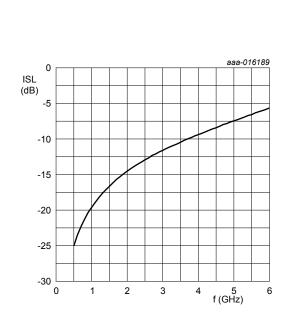
Figure 1. Diode capacitance as a function of reverse voltage; typical values



f = 100 MHz;  $T_j = 25 \,^{\circ}\text{C}$ .

Figure 2. Forward resistance as a function of forward current; typical values

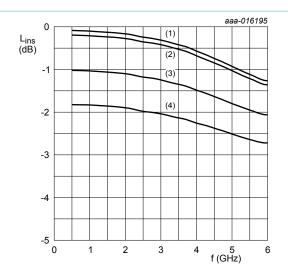
Silicon PIN diode



 $T_{amb} = 25 \, ^{\circ}C$ 

Diode zero biased and inserted in series with a 50  $\Omega$  stripline circuit

Figure 3. Isolation of the diode as a function of frequency; typical values



 $T_{amb} = 25 \, ^{\circ}C$ 

1. I<sub>F</sub> = 100 mA

2. I<sub>F</sub> = 10 mA

3.  $I_F = 1 \text{ mA}$ 

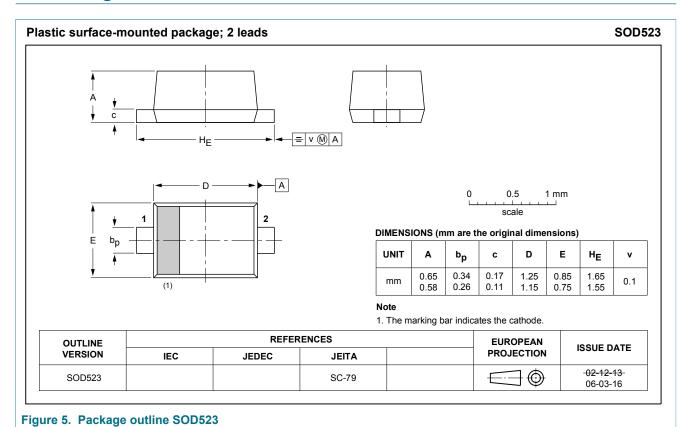
4.  $I_F = 0.5 \text{ mA}$ 

Diode inserted in series with a 50  $\Omega$  stripline circuit and biased via the analyzer Tee network

Figure 4. Insertion loss of the diode as a function of frequency; typical values

Silicon PIN diode

# 8 Package outline



# 9 Abbreviations

Table 7. Abbreviations

| Tuble 1. Abbreviations |                            |  |  |  |
|------------------------|----------------------------|--|--|--|
| Acronym                | Description                |  |  |  |
| AQL                    | acceptable quality level   |  |  |  |
| PIN                    | P-type, intrinsic, N-type  |  |  |  |
| SMD                    | surface mounted device     |  |  |  |
| S4                     | special inspection level 4 |  |  |  |

# 10 Revision history

Table 8. Revision history

| Document ID    | Release date                  | Data sheet status                           | Change notice | Supersedes    |
|----------------|-------------------------------|---|---------------|---------------|
| BAP64-02 v.11  | 20190311                      | Product data sheet                          | -             | BAP64-02 v.10 |
| Modifications: | • changed V <sub>R</sub> cond | dition of I <sub>R</sub> from 175 V to 60 V |               |               |
| BAP64-02 v.10  | 20150512                      | Product data sheet                          | -             | BAP64-02 v.9  |
| Modifications: | AEC-Q101 qualif               | ied   |               |               |
| BAP64-02 v.9   | 20141215                      | Product data sheet                          | -             | BAP64-02 v.8  |

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| Document ID                        | Release date | Data sheet status         | Change notice | Supersedes     |
|------------------------------------|--------------|---------------------------|---------------|----------------|
| BAP64-02 v.8                       | 20140428     | Product data sheet        | -             | BAP64-02 v.7   |
| BAP64-02 v.7                       | 20140211     | Product data sheet        | -             | BAP64-02_N v.6 |
| BAP64-02_N v.6                     | 20080109     | Product data sheet        | -             | BAP64-02 v.5   |
| BAP64-02 v.5 (9397 750 06912)      | 20000323     | Product specification     | -             | BAP64-02 v.4   |
| BAP64-02 v.4 (9397 750 06418)      | 19990921     | Preliminary specification | -             | BAP64-02_N v.3 |
| BAP64-02_N v.3 (9397<br>750 06086) | 19990616     | Preliminary specification | -             | BAP64-02 v.2   |
| BAP64-02 v.2 (9397 750 05556)      | 19990510     | Objective specification   | -             | BAP64-02_N v.1 |
| BAP64-02_N v.1 (9397<br>750 05492) | 19981204     | Objective specification   | -             | -              |

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### 11 Legal information

#### 11.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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